# NSN 5962-01-294-4753

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## **Body Length:**

Between 0.755 inches and 0.785 inches

## **Body Width:**

0.302 inches

## **Body Height:**

Between 0.145 inches and 0.175 inches

## **Maximum Power Dissipation Rating:**

332.8 milliwatts

## **Operating Tempurature Range:**

+0.0/+70.0 degrees celsius

## Storage Tempurature Range:

-55.0/+150.0 degrees celsius

## **End Application:**

Radar set an/aps-133v2

#### **Features Provided:**

Hermetically sealed and programmable and bipolar and w/enable

## Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## Output Logic Form:

Transistor-transistor logic

## Input Circuit Pattern:

6 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level

output

## Memory Device Type:

Rom

## **Memory Capacity:**

Unknown

## **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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